

SINGLE CHANNEL IL30/31/55 DUAL CHANNEL ILD30/31/55 QUAD CHANNEL ILQ30/31/55 PHOTODARLINGTON OPTOCOUPLER

FEATURES

- **Current Transfer Ratio**
IL/D/Q30/55, 100% Min.
IL/D/Q31, 200% Min.
- **125 mA Load Current Rating**
- **Fast Rise Time, 10 μ S**
- **Fast Fall Time, 35 μ S**
- **Single, Dual, & Quad Channel**
- **Solid State Reliability**
- **Standard DIP Package**
- **Underwriters Lab File #E52744**
-  **VDE 0884 Available with Option 1**

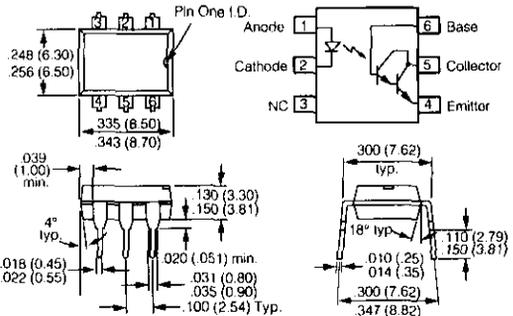
DESCRIPTION

The IL30/31/55, ILD30/31/55 and ILQ30/31/55 are optically coupled isolators with a Gallium Arsenide infrared emitter and a silicon photodarlington sensor. Switching can be achieved while maintaining a high degree of isolation between driving and load circuits, with no cross talk between channels. These optocouplers can be used to replace reed and mercury relays with advantages of long life, high speed switching and elimination of magnetic fields.

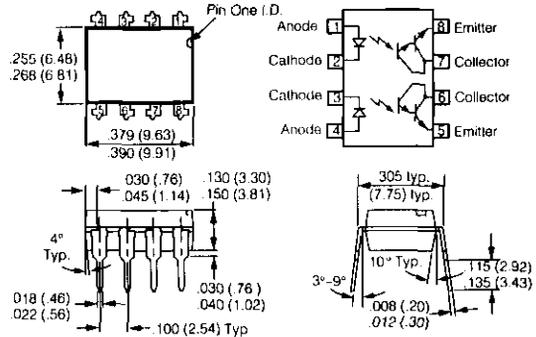
The IL30/31/55 are equivalent to MCA230/MCA231/MCA255. The ILD/Q30/31/55 are designed to reduce board space requirements in high density applications.

Package Dimensions in Inches (mm)

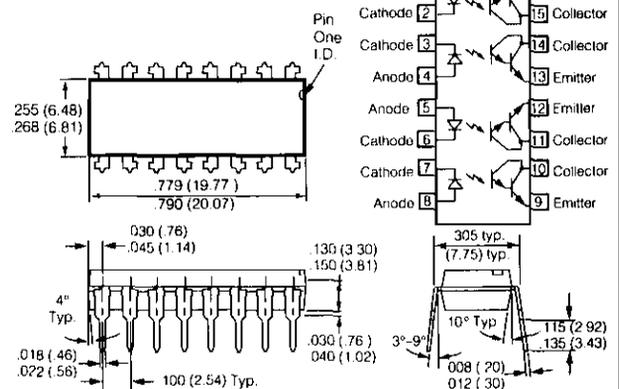
IL30/31/55 (Single Channel)



ILD30/31/55 (Dual Channel)



ILQ30/31/55 (Quad Channel)



Maximum Ratings

Emitter (each channel)

Peak Reverse Voltage	3 V
Continuous Forward Current	60 mA
Power Dissipational 25°C	100 mW
Derate Linearly from 25°C	1.33mW/°C

Detector (each channel)

Collector-Emitter Breakdown Voltage IL/D/Q30	30 V
Collector-Emitter Breakdown Voltage IL/D/Q55	55 V
Collector (Load) Current	125 mA
Power Dissipation at 25°C Ambient	150 mW
Derate Linearly from 25°C	2.0 mW/°C

Package

Total Package Dissipation at 25°C	
IL30/31/55	250 mW
ILD30/31/55	400 mW
IL7Q30/31/55	500 mW
Derate Linearly from 25°C	
IL30/31/55	3.3 mW/°C
ILD30/31/55	5.33 mW/°C
ILQ30/31/55	6.67 mW/°C
Isolation Test Voltage	5300 VAC _{RMS}
Creepage	7 mm min.
Clearance	7 mm min
Comparative Tracking Index	175
Storage Temperature	-55°C to +125°C
Operating Temperature	-55°C to +100°C
Lead Soldering Time at 260°C	10 sec.

Electrical Characteristics (T_A=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Emitter						
Forward Voltage	V _F	1.25	1.5		V	I _F = 20 mA
Reverse Current	I _R	0.1	10		μA	V _R = 3.0 V
Capacitance	C _O	25			pF	V _R = 0
Detector						
Collector-Emitter Breakdown Voltage	BV _{CEO}	30/55			V	I _C = 100 μA
Collector-Emitter Leakage Current	I _{CEO}	1.0	100		nA	V _{CE} = 10 V, I _F = 0
Collector-Emitter Capacitance	C _{CE}	3.4			pF	V _{CE} = 10 V f = 1 MHz
Package						
Current Transfer Ratio						
IL/D/Q30/55	CTR	100	400		%	I _F = 10 mA, V _{CE} = 5 V
IL/D/Q31		200	400		%	I _F = 10 mA, V _{CE} = 5 V
Collector-Emitter Saturation Voltage	V _{CEsat}	0.9	1.0		V	I _C = 50 mA, I _F = 50 mA
Isolation Test Voltage		5300			VAC _{RMS}	
Isolation Resistance	R _{ISOL}	10 ¹²			Ω	
Coupling						
Capacitance	C _{ISOL}	0.5			pF	
Rise Time	t _r	10			μs	V _{CC} = 13.5 V I _F = 50 mA R _C = 100 Ω
Fall Time	t _f	35			μs	

Figure 1. Forward voltage versus forward current

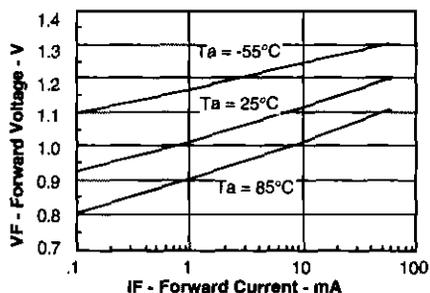


Figure 2. Normalized non-saturated and saturated CTR_{ce} at T_A=25°C versus LED current

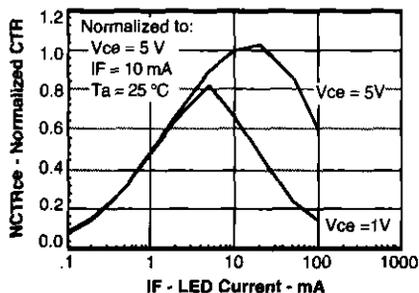


Figure 3. Normalized non-saturated and saturated collector-emitter current versus LED current

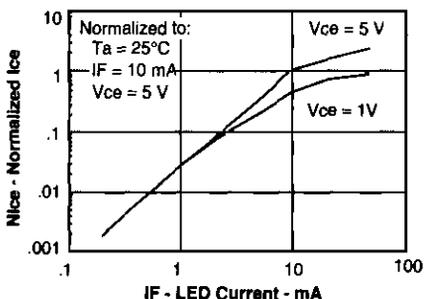


Figure 4. Normalized collector-base photocurrent versus LED current

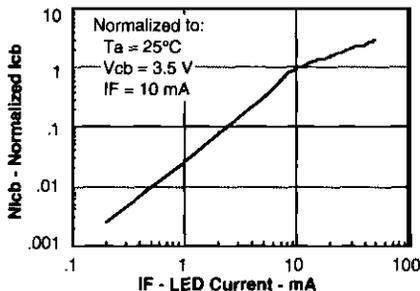


Figure 5. Hfe current gain vs. base current

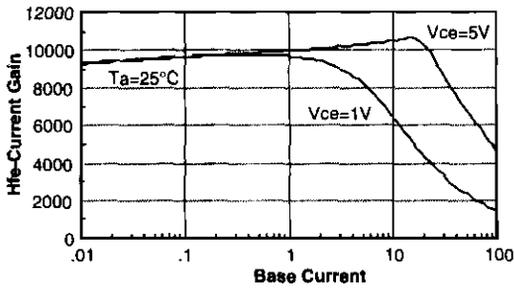


Figure 7. High to low propagation delay versus collector load resistance and LED current

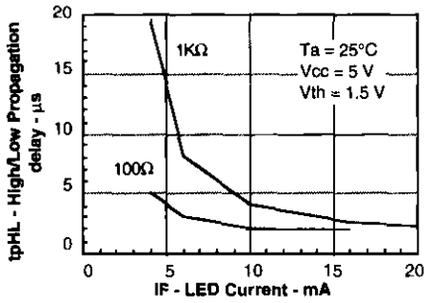


Figure 9. Switching schematic

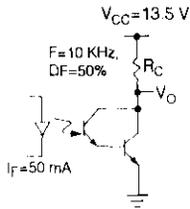


Figure 6. Low to high propagation delay versus collector load resistance and LED current

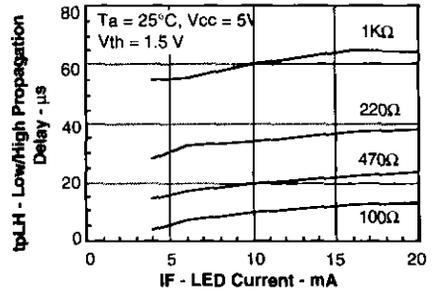


Figure 8. Switching waveforms

